

UNIVERSITI TUN HUSSEIN ONN MALAYSIA

FINAL EXAMINATION SEMESTER I SESSION 2010/2011

COURSE NAME

: BASIC ELECTRIC AND ELECTRONICS

COURSE CODE : DKE 3273

PROGRAMME : 3 DDT

EXAMINATION DATE : NOVEMBER/DECEMBER 2010

DURATION

INSTRUCTIONS

: ANSWER FIVE (5) QUESTIONS ONLY

THIS QUESTION PAPER CONSISTS OF TEN (10) PAGES

: 3 HOURS

Q1 Refer to Figure Q1, show all the calculation to find the value for;

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Q2

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a)	Total resistance R _T
	(4 marks)
b)	The voltage drop across resistance R_2 (V _{R2}), resistance R_3 (V _{R3}), resistance R_4 (V _{R4}) and resistance R_6 (V _{R6})
	(8 marks)
c)	The current flow through resistance R_2 (I_{R2}), resistance R_3 (I_{R3}), resistance R_4 (I_{R4}) and resistance R_6 (I_{R6})
	(8 marks)
a)	An electromagnet produces a magnetic flux of 900μ Wb. Determine the magnetic field lines.
	(10 marks)
b)	Calculate the flux density, in gauss units for a flux, \emptyset , of 200µWb in a cross sectional area of 5 x 10 ⁻⁴ m ² .

(10marks)

Q3 a) Determine the amount of charge, Q, stored by a capacitor if

- i) $C = 10\mu F$ and V = 5V
- ii) C = 680 pF and V = 200 V
- iii) $C = 0.22 \ \mu F$ and $V = 50 \ V$

(6 marks)

- b) Determine the voltage, V, across a capacitor if
 - i) $Q = 2.5 \ \mu C$ and $C = 0.01 \ \mu F$
 - ii) $Q = 10 \text{ mC} \text{ and } C = 1000 \ \mu\text{F}$
 - iii) Q = 188 nC and $C = 0.0047 \,\mu\text{F}$

(6 marks)

- c) Calculate the capacitance, C, of a capacitor for each set of physical characteristics listed below;
 - i) $A = 0.1 \text{ cm}^2$, d = 0.005 cm, $K\epsilon = 1$
 - ii) $A = 1 \text{ cm}^2$, $d = 5 \times 10^{-6} \text{ cm}$, $K\epsilon = 6$

(8 marks)

Refe	to Figure Q4, assume a charging current of 2.4 mA flows for 1 ms, de	termine;
a)	Total equivalent capacitance, C _{EQ}	
b)	The charge stored each capacitor C_1 , (Q_{C1}) , $C_2(Q_{C2})$ and $C_3(Q_{C3})$	(4 marks)
c)	The voltage across each capacitor C_1 (V_{C1}), C_2 (V_{C2}) and C_3 (V_{C3})	(6 marks)
d)	The total charge, O_T stored by the equivalent capacitor. C_{FO}	(6 marks)
		(4 marks)
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Q5 Refer to Figure Q5, calculate;

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Q4

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a)	The secondary voltage, V_S		
b)	The secondary current, Is	(4 marks)	
c)	The secondary power, P _S	(4 marks)	
d)	The primary power, P _P	(4 marks)	
e)	The primary current, I _P	(4 marks)	
		(4 marks)	
Refer to Figure Q6, determine;			

Q6	Refer to	Figure	Q6,	determine
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a)	The total equivalent resistance, R _{EQ}	
b)	The branch currents, I_1 and I_2	(4 marks)
c)	The total current, I_T	(4 marks)
d)	The power dissipated at each resistors P ₁ and P ₂	(4 marks)
e)	The total power supplied by the source $P_{\rm m}$	(4 marks)
,	to an power supplied by the source, I T	(4 marks)

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Q7	(a)	Figur	e Q7(a) shows a transistor biasing circuit;	
		i)	calculate collector saturation current (I _{C(sat)})	
		ii)	calculate collector-emitter off voltage (V _{CE (off)})	(1 mark)
		iii)	calculate current at the Ω -point (I _{ac})	(1 mark)
)	calculate current at the Q-point (ICQ)	(3 marks)
		1V)	calculate voltage at the Q-point (V_{CEQ})	(1 mark)
		v)	draw the DC load line for the transistor circuit	(4 marks)
	(b) Figure Q7(b) shows a n-channel JFET circuit. What is the provide drain current (Ip) of approximately one-half Ipper?		e Q7(b) shows a n-channel JFET circuit. What is the value of R le drain current (I _D) of approximately one-half I _{DSS} ?	s that will
				(2 marks)
	(c)	Referr detern	ring to Figure Q7(b), for the values of R_s calculated in quest nine:	ion Q7(b),
		i)	gate voltage (V _G)	
		ii)	source voltage (V _s)	(2 marks)
		iii)	gate-source voltage (V _{cs})	(2 marks)
		iv)	drain voltage (V _D)	(2 marks)

(2 marks)











References :

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Band Color	Digit	Multiplier	Tolerance
Black	0	1	
Brown	1	10	±1%
Red	2	100	±2%
Orange	3	1,000	±3%
Yellow	4	10,000	±4%
Green	5	100,000	
Blue	6	1,000,000	
Violet	7	10,000,000	
Gray	8	100,000,000	
White	9		
Gold		0.1	±5%
Silver		0.01	±10%
None			±20 %